

# Final Product/Process Change Notification Document #:FPCN22966Zl1 Issue Date:07 Sep 2021

Title of Change:	Wafer Fab Transfer for Trench 6 MOSFET Technology to Global Foundries in New York, US with additional clip change for device NVMFS5C442NL		
Proposed Changed Material First Ship Date:	08 Jan 2022 or earlier if approved by customer		
Current Material Last Order Date:	26 Nov 2021 Orders received after the Current Material Last Order Date expiration are to be considered as orders for new changed material as described in this PCN. Orders for current (unchanged) material after this date will be per mutual agreement and current material inventory availability.		
Current Material Last Delivery Date:	07 Jan 2022 The Current Material Last Delivery Date may be subject to change based on build and depletion of the current (unchanged) material inventory		
Product Category:	Active components – Discrete components		
Contact information:	Contact your local onsemi Sales Office or <u>Ammar.Anuar@onsemi.com</u>		
PCN Samples Contact:	Contact your local onsemi Sales Office to place sample order or < <u>PCN.samples@onsemi.com</u> >. Sample requests are to be submitted no later than 45 days after publication of this change notification. Samples delivery timing will be subject to request date, sample quantity and special customer packing/label requirements.		
Sample Availability Date:	01 Jan 2021		
PPAP Availability Date:	01 Jan 2021		
Additional Reliability Data:	Contact your local onsemi Sales Office or <u>Robert.Baran@onsemi.com</u>		
Type of Notification:	This is a Final Product/Process Change Notification (FPCN) sent to customers. The change we be implemented at 'Proposed Change Material First Ship Date' in compliance to J-STD-46 or ZVEI, or earlier upon customer approval, or per our signed agreements. onsemi will consider this proposed change and it's conditions acceptable, unless an inquiry made in writing within 45 days of delivery of this notice. To do so, contact PCN.Support@onsemi.com.		
Change Category			
Category	Type of Change		
Packing/Shipping	Dry pack requirements change		
Test Flow	Move of all or part of electrical wafer test and/or final test to a different location/site/subcontractor		
Process - Wafer Production	Move of all or part of wafer fab to a different location/site/subcontractor, New wafer diameter		
Process - Assembly	Move of all or part of assembly to a different location/site/subcontractor., Change in process technology (e.g., plating) Change of specified assembly process sequence (deletion and/or additional process step)		

# **Description and Purpose:**

This Product Change Notification, is an update to FPCN22966ZI, specifically on device NVMFS5C442NL series, which is intended to qualify a new clip design for SO8FL package assembly in onsemi Seremban, Malaystia. New clip design is to improve package robustness for better product performance.

As per FPCN22966ZI, the changes also includes the increase of capacity for onemi automotive 40V Trench 6 MOSFET technology products by transferring wafer fabrication for these products to the Global Foundries Fab located in New York, US.

The changes include transferring wafer fabrication, back grind and back metal, to Global Foundries, and utilizing 300mm instead of 200mm diameter wafers. And while the assembly location remains unchanged (at onsemi, Seremban, Malaysia), wafer saw and die attach tooling are being updated to accommodate 300mm wafers.



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Inere is no pro	duct marking change as	a result of	-	re Change	After Change	<b>a</b>	
Wafer Fabrication Site		onsemi Aizu, Japan onsemi Gresham, US		Global Foundries, US			
	Wafer Diameter		200mm (existing sites)		300mm (Global Foundries)		
	Wafer Probe Site			ni, Malaysia	<u>Global Foundries, US</u>		
Back	Grind, Back Metal Site			ni, Malaysia	Global Foundries, US		
Clip Change							
Reason / Mot	tivation for Change:	Source/S	upply/Capacity Cha	nges Process/Materials Cha	nge		
Anticipated impact on fit, form, function, reliability, productsuccess performsafety or manufacturability:		successf performe	vice has been qualified and validated based on the same Product Specification. The device has sfully passed the qualification tests. Potential impacts can be identified, but due to testing ned by onsemi in relation to the PCN, associated risks are verified and excluded. icipated impacts.				
Sites Affected	d:						
onsemi Sites				External Foundry/Subcon Sites			
onsemi Gresha	m, United States			GlobalFoundries, Fab 10, New York, US			
onsemi Aizu, Ja	pan						
onsemi Seremb	oan, Malaysia						
onsemi ISMF, N	1alaysia						
Marking of Parts/ Traceability of Change:							
RMS: <u>66099, 6</u> PACKAGE: <u>SO8</u>	ME (DIE QUAL): <u>NVMFS5</u> 7744, 67566, 67567 FL-HE						
Test	Specificatio			Condition	Interval	Results	
HTRB	JESD22-A108	8 Ta=175°C, 100%		max rated Vds	2016 hrs	0/231	
HTGB	JESD22-A108	,		max rated Vgss	2016 hrs	0/231	
HTSL	JESD22-A103		Ta= 175°C		2016 hrs	0/231	
MIL-STD-750 Ta=+25°C, delta T   IOL (M1037) On/off =2 min   AEC-Q101 On/off =2 min		-j=100°C	30000 cyc	0/231			
TC JESD22-A104 Ta= -55°C to +		Ta= -55°C to +150	1°C	1000 cyc	0/231		



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HAST	JESD22-A110	130°C, 85% RH, 18.8psig, bias	192 hrs	0/231
uHAST	JESD22-A118	130°C, 85% RH, 18.8psig, unbiased	96 hrs	0/231
PC	J-STD-020 JESD-A113	MSL1 @ 260°C		
RSH	JESD22- B106	Ta = 265C, 10 sec		0/30

### QV DEVICE NAME (DIE QUAL): <u>NVMFS5C404N</u> RMS: <u>66100</u>

PACKAGE: SO8FL-HE

Test	Specification	Condition	Interval	Results
HTGB	JESD22-A108	Ta=175°C, 100% max rated Vgss	2016 hrs	0/231

#### QV DEVICE NAME (DIE QUAL): <u>NVMFS5C645NLT1G</u> RMS: <u>45829</u>

#### PACKAGE: SO8FL

Test	Specification		Condition	Interval	Results
AC	JESD22 A102		JESD22 A102 Ta = 121°C, P= 15 PSIG, RH = 100%, 96 Hours		0/231
H3TRB	JESD22-A101		Temp = 85C, RH=85%, bias = 80% of rated V or 100V max	2016 hrs	0/231
TC+PC	JESD22-A104		Ta = -55°C to +150°C	1000 сус	0/231
IOL+PC	MIL STD750, M 1037 AEC Q101		Ta=+25°C, deltaTj=100°C max, Ton = Toff = 2min	30000 cyc	0/231
PC	J-STD-020 JESD-A113		MSL 1 @ 260 °C		0/504
RSH	JESD22-B106		Ta = 265°C, 10 sec		0/90
SD	JSTD002		Ta = 245°C, 10 sec		0/45

# **Electrical Characteristics Summary:**

Electrical characteristics are not impacted.

## List of Affected Parts:

**Note:** Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the **PCN Customized Portal**.

Current Part Number	New Part Number	Qualification Vehicle			
NVMFS5C442NLT3G	NA	NVMFS5C404NWFT3G-K, NVMFS5C404NLT1G, NVMFS5C645NLT1G			
NVMFS5C442NLT1G	NA	NVMFS5C404NWFT3G-K, NVMFS5C404NLT1G, NVMFS5C645NLT1G			
NVMFS5C442NLAFT3G	NA	NVMFS5C404NWFT3G-K, NVMFS5C404NLT1G, NVMFS5C645NLT1G			
NVMFS5C442NLAFT1G	NA	NVMFS5C404NWFT3G-K, NVMFS5C404NLT1G, NVMFS5C645NLT1G			



# Appendix A: Changed Products

Product	Customer Part Number	Qualification Vehicle	New Part Number	Replacement Supplier
NVMFS5C442NLAFT1G		NVMFS5C404NWFT3G-K,	NA	
		NVMFS5C404NLT1G,		
		NVMFS5C645NLT1G		